1165917





High-current complementary silicon transistors.

For use output devices in complementary general purpose amplifier applications. **Features:**

- High DC current gain h_{FE} = 1000 (minimum) at I_C 20A dc.
- Monolithic construction with built-in base emitter shunt resistor.
- Junction temperature to +200°C.

(TO-3)



Style 1:

Pin 1. Base 2. Emitter Collector (Case)

Dimensions	Minimum	Maximum	
A	1.550 (39.37) Reference		
В	-	1.050 (26.67)	
С	0.250 (6.35)	0.335 (8.51)	
D	0.038 (0.97)	0.043 (1.09)	
E	0.055 (1.40)	0.070 (1.77)	
G	0.430 (10.92) BSC		
Н	0.215 (5.46) BSC		
к	0.440 (11.18) 0.480 (12		
L	0.665 (16.89) BSC		
N	-	0.830 (21.08)	
Q	0.151 (3.84)	0.165 (4.19)	
U	1.187 (30.15) BSC		
V	0.131 (3.33)	0.188 (4.77)	
Dimensions : Inches (Millimetres			

30 Ampere Darlington Power Transistors Complementary Silicon 60 - 120 Volts, 200 Watts



Emitter 2



(TO-3) Case 1-07 Style 1



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Maximum Ratings

Rating	Symbol	Value	Unit	
Collector-Emitter Voltage MJ11015	V _{CEO}	120		
Collector-Base Voltage MJ11015	V _{CB}		V dc	
Emitter-Base Voltage	V _{EB}	5		
Collector Current	۱ _C	30	A do	
Base Current	Ι _Β	1		
Total Device Dissipation at T _C = 25°C Derate above 25°C at TC = 100°C	P _D	200 1.15	W W/°C	
Operating and Storage Junction Temperature Range	T _{J,} T _{stg}	-55 to +200	°C	

Thermal Characteristics

Characteristics	Symbol	Maximum	Unit
Thermal Resistance, Junction-to-Case	$R_{ extsf{ heta}JC}$	1.17	°C/W
Maximum Lead Temperature for Soldering Purposes for ≤10 Seconds	TL	275	°C

Stresses exceeding maximum ratings may damage the device. Maximum ratings are stress ratings only. Functional operation above the recommended operating conditions is not implied. Extended exposure to stresses above the recommended operating conditions may affect device reliability.

Darlington Circuit Schematic







Electrical Characteristics (T_c = 25°C unless otherwise noted)

Characteristic		Symbol	Minimum	Maximum	Unit
Off Characteristics			1		
Collector-Emitter Brakdown Voltage (1) ($I_c = 100$ mA dc, $I_B = 0$)	MJ11015	V (BR) CEO	120	-	V dc
Collector-Emitter Leakage Current (V_{CE} = 120V dc, R_{BE} = 1k Ω) (V_{CE} = 120V dc, R_{BE} = 1k Ω , T_{C} = 150°C)	MJ11015 MJ11015	I _{CER}	-	1 5	
Emitter Cut off Current (V_{BE} = 5.0V dc, I _C = 0)		I _{EBO}	-	5	mA dc
Collector-Emitter Leakage Current (V _{CE} = 5.0V dc, I _B = 0)		I _{CEO}	-	1	
On Characteristics (1)					
DC Current Gain ($I_C = 20A dc$, $V_{CE} = 5V dc$ ($I_C = 30A dc$, $V_{CE} = 5V dc$)		h _{FE}	1000 200		-
Collector-Emitter Saturation Voltage ($I_C = 20A dc$, $I_B = 200mA dc$) ($I_C = 30A dc$, $I_B = 300mA dc$)		V _{CE (sat)}	-	3 4)/ dc
Base-Emitter Saturation Voltage ($I_C = 20A dc$, $I_B = 200mA dc$) ($I_C = 30A dc$, $I_B = 300mA dc$)		V _{BE (sat)}	-	3.5 5	v uc
Dynamic Characteristics					
Current-Gain Bandwidth Product (I _C = 10A, V _{CE} = 3V dc, f = 1MHz)		h _{fe}	4	-	MHz

(1) Pulse Test: Pulse Width = 300μ S, Duty Cycle $\leq 2.0\%$.











Active Region DC Safe Operating Area



There are two limitations on the power handling ability of a transistor average junction temperature and secondary breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operations e.g., the transistor must not be subjected to greater dissipation than the curves indicate. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by secondary breakdown.

Part Number Table

Description	Part Number	
Darlington Transistor, TO-3	MJ11015	

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